LME49600 Headphone Amplifier Evaluation Board User's Guide

National Semiconductor
Application Note 1768
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Quick Start Guide

Apply a ±2.5V to ±17V power supply's voltage to the respective "V+", "GND" and "V-" pins on JU19

Apply a stereo audio signal to the RCA jacks J1 (Right) and J2 (Left) or jumpers JU1 (Right) and JU17 (Left), observing the signal input pin and the ground (GND) pin. Though not typically installed, a stereo signal can also be applied to headphone jack HPJ1.

Connect a load to JU14 (Left) and another load to JU15 (Right), observing the signal output pin and the ground (GND) pin. The stereo signal output is also available on the 1/8" stereo headphone jack located in the board's "OUTPUT" section

Use VR1 to control the output signal amplitude.

Apply power. Make measurements. Plug in a pair of headphones. Enjoy.

Introduction

To help the user investigate and evaluate the LME49600's performance and capabilities, a fully populated demonstration board was created. Please contact the National Semiconductor Corporation's Audio Products Group for availability. This board is shown in Figure 1. Connected to an external power supply (±2.5V to ±17V) and a signal source. The LME49600 demonstration board easily demonstrates the amplifier's features.

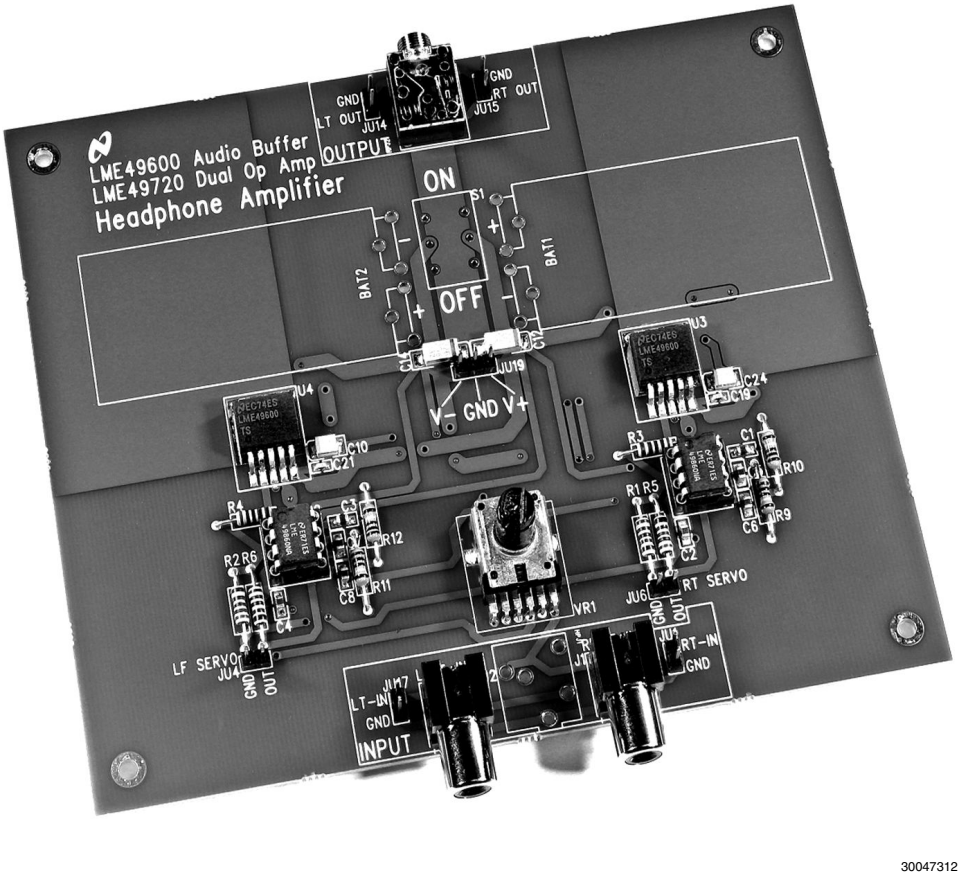

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FIGURE 1. The LME49600/LME49720 Stereo Headphone Amplifier Demonstration Board

General Description

The LME49600 is a high performance, low distortion high fidelity 250mA audio buffer. Whereas there are many uses for the LME49600, this application note describes a headphone amplifier circuit and associated demonstration board. Designed for use inside an operational amplifier's feedback loop, it increases output current, improves capacitive load drive, and eliminates thermal feedback.

The LME49600 offers a pin-selectable bandwidth: a low current, 110MHz bandwidth mode that consumes 8mA and a wide 180MHz bandwidth mode that consumes 15mA. In both modes the LME49600 has a nominal 2000V/µs slew rate. Bandwidth is easily adjusted by either leaving the BW pin unconnected, connecting a resistor between the BW pin and the V_{EE} pin or connecting the BW pin directly to the V_{EE} pin.

The LME49600 is fully protected through internal current limit and thermal shutdown.

Operating Conditions

- Temperature Range $-40°C \leq T_A \leq 85°C$
- Amplifier Power Supply Voltage $2.5V \leq V_S \pm 17V$

Board Features

The LME49600/LME49720 Stereo Headphone Amplifier demonstration board has all of the necessary connections, using RCA jacks, 1/8" stereo headphone jack and 0.100" headers, to apply the power supply voltage and the audio input signals. The amplified audio signal is available on both a stereo headphone jack and auxiliary output connections.

Also present on the demonstration board is a potentiometer to control the stereo output signal magnitude.

Schematic

Figure 2 shows the LME49600/LME49720 Stereo Headphone Amplifier Demonstration Board schematic. Refer to Table 3 for a list of the connections and their functions.

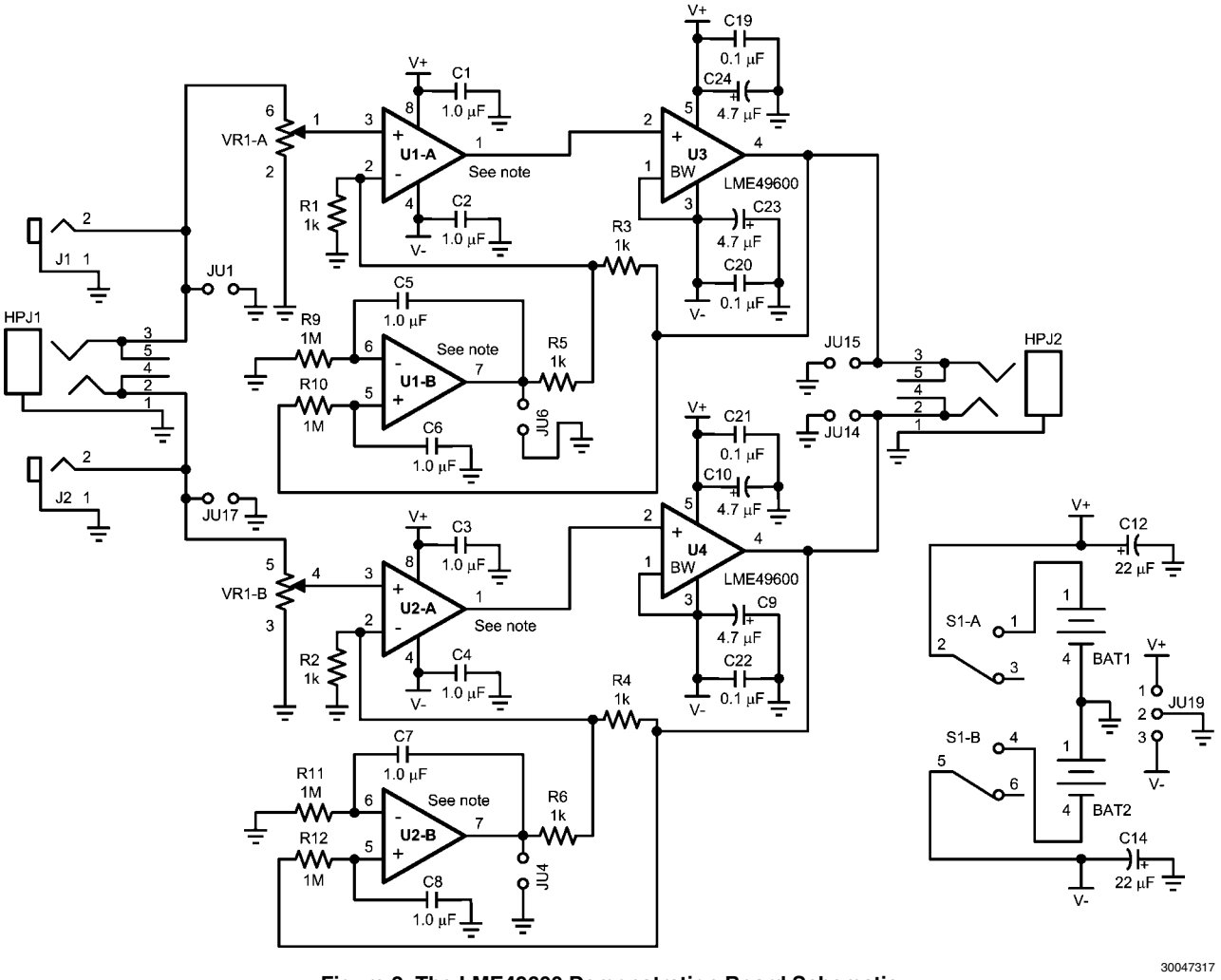

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Figure 2. The LME49600 Demonstration Board Schematic
Note: The LM4562, LME49720, or LME49860 can be used.

Connections

Connecting to the world is accomplished through a combination of RCA jacks, 1/8” stereo headphone jacks and 0.100” headers on the LME49600 demonstration board. The functions of the different headers, 1/8” headphone jacks and RCA jacks are detailed in Table 1.

TABLE 1. LME49600 Demonstration Board Connections

Designator	Function or Use
JU17	This is the connection to the amplifier’s left channel input. Apply an external signal source’s positive voltage to the JU17 pin labeled “LT IN” and the signal source’s ground signal to the pin labeled “GND.”
J2	This is an RCA connector that parallels the pins on JU17.
HPJ1	Stereo, 1/8” headphone jack. Used for stereo signal input. Left channel input is on the tip connector and the right channel input is on the ring connector. Ground is on the sleeve connector.
J1	This is an RCA connector that parallels the pins on JU1.
JU1	This is the connection to the amplifier’s right channel input. Apply an external signal source’s positive voltage to the JU1 pin labeled “RT IN” and the signal source’s ground signal to the pin labeled “GND.”
JU19	Power supply connection. Connect an external split power supply’s voltage source ±2.5V to ±17V to the JU19 pin labeled (“V+” and “V-”)” and the supply’s ground source to the pin labeled “GND.”
JU14	This is the connection to the amplifier’s single-ended, ground-referenced left channel output. Connect the JU14 pin labeled “LT OUT” and the pin labeled “GND” to the positive and ground inputs, respectively, of an external signal measurement device. JU14’s pin labeled “LT OUT” corresponds to the headphone jack’s “tip” connection. J5’s pin labeled “GND“ corresponds to the headphone jack’s “sleeve” (or ground) connection.
HPJ2	Stereo, 1/8” headphone jack. Used for stereo signal output. Left channel output is on the tip connector and the right channel output is on the ring connector. Ground is on the sleeve connector.
JU15	This is the connection to the amplifier’s ground-referenced right channel output. Connect the JU15 pin labeled “RT OUT” and the pin labeled “GND” to the positive and ground inputs, respectively, of an external signal measurement device. JU15’s pin labeled “RT OUT” corresponds to the headphone jack’s “ring” connection. J4’s pin labeled “GND“ corresponds to the headphone jack’s “sleeve” (or ground) connection.
JU4, JU6	These connections allow monitoring the left and right channel DC servo outputs, respectively.

PCB Layout Guidelines

This section provides general practical guidelines for PCB layouts that use various power and ground traces. Designers should note that these are only "rule-of-thumb" recommendations and the actual results are predicated on the final layout.

POWER AND GROUND CIRCUITS

Star trace routing techniques can have a major positive impact on low-level signal performance. Star trace routing refers to using individual traces that radiate from a signal point to feed power and ground to each circuit or even device.

Bill of Materials

RefDes	Part Description	Value	Tolerance	Rating	Package Type	Manufacturer and Part Number
BAT1– BAT2	9V Battery Terminal (male & female) [Not Installed]					KEYSTONE 593 (Female) & 594 (Male)
C1 – C8	MULITYLAYER CERAMIC CAPACITOR	1.0µF	±20%	25V	805	TDK C2012X5R1E105M
C9 C10, C23 – C24	TANTALUM ELECTROLYTIC CAPACITOR	4.7µF	±10%	35V	B CASE	AVX TPSB475K035R0700
C12, C14		22µF	±20%	25V	C CASE	AVX TPSD226M025#011
C19 – C22	CERAMIC CAPACITOR	0.1µF	±10%	25V	603	TDK C1608X7R1E104K
HPJ1– HPJ2	1/8” Stereo Headphone Jack					
J1 – J2	RCA jack					
JU1, JU4, JU6, JU14, JU15, JU17	100mil pin pitch, two pin					
JU19	100mil pin pitch, three pin					
R1 – R6	1/4W resistor	1kΩ	±1%	1/4W	1/4W, Axial	YAGEO MFR-25FBF-1K00
R9 – R12	1/4W resistor	1MΩ	±1%	1/4W	1/4W, Axial	YAGEO MFR-25FBF-1M00
S1	SWITCH SLIDE DPDT [Not Installed]	DPDT				
U1, U2	LME49720NA (Can also use LM4562, LME49860)					National Semiconductor Corp. LME49720NA (LM4562NA or LME49860NA)
U3, U4	LME49600					National Semiconductor Corp. LME49600TS
VR1	Dual gauged potentiometer	10kΩ				PANASONIC EVJ-Y00F30A14

Demonstration Board PCB Layout

Figures 3 through 6 show the different layers used to create the LME49600 demonstration board. Figure 3 is the silkscreen that shows parts location. Figure 4 is the top layer. Figure 5 is the bottom layer. Figure 6 is the bottom silkscreen layer.

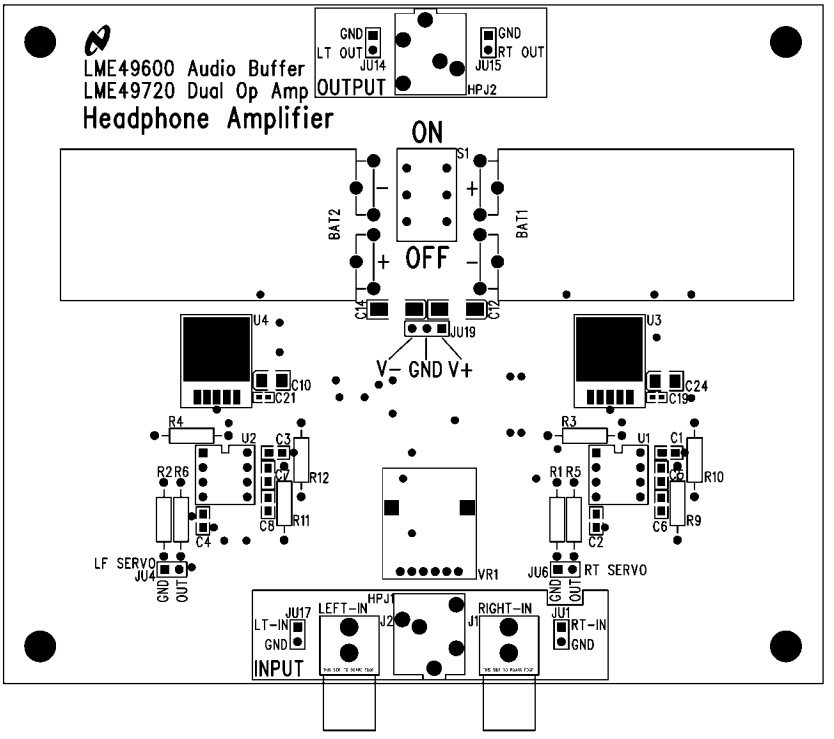

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Figure 3. Top Silkscreen

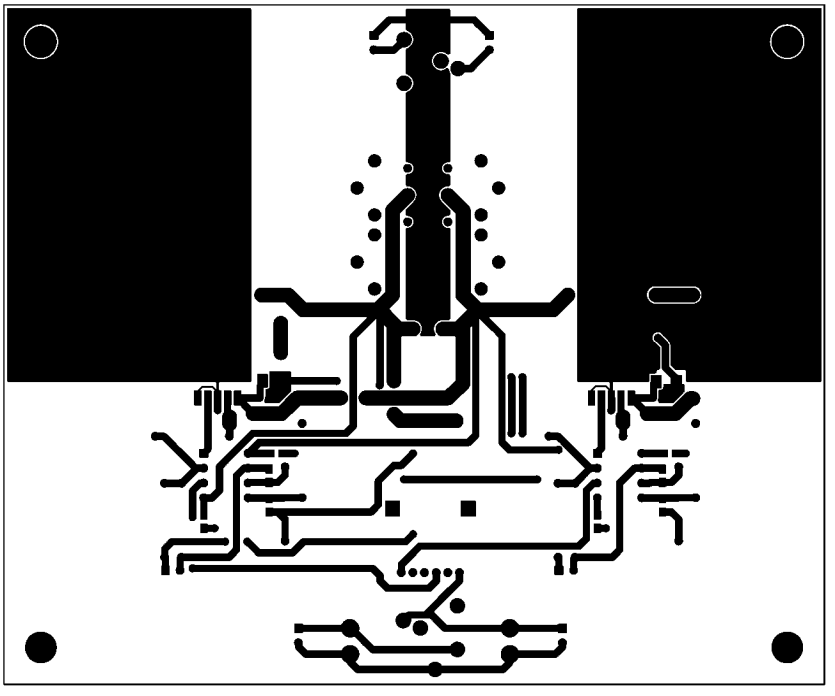

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Figure 4. Top Layer

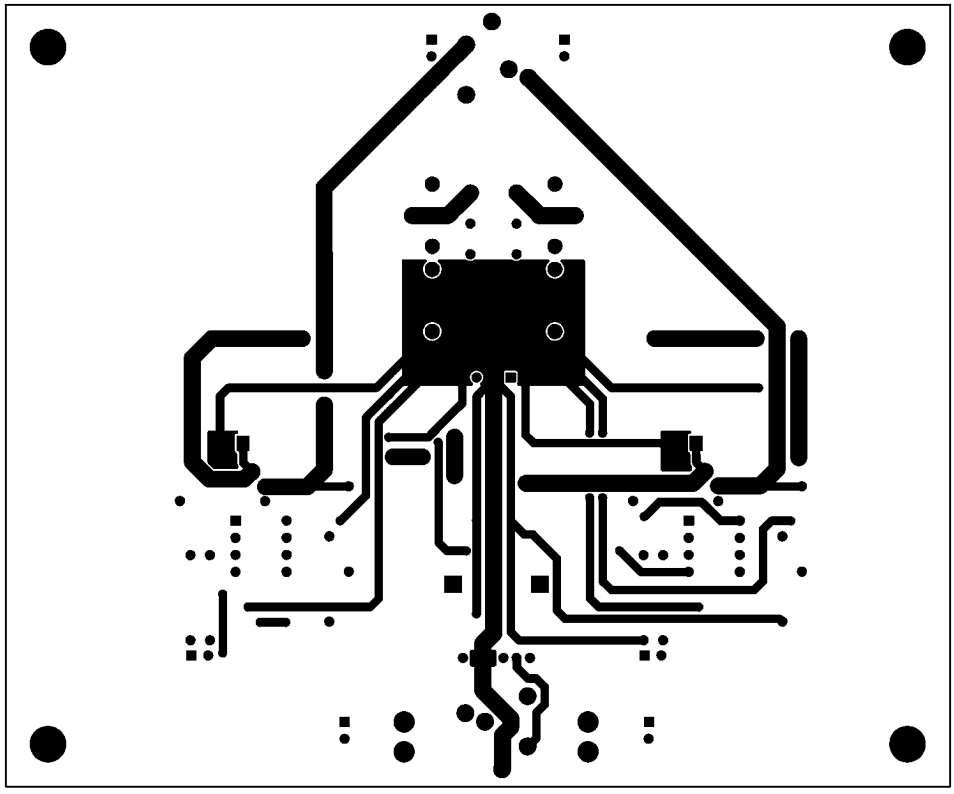

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Figure 5. Bottom Layer

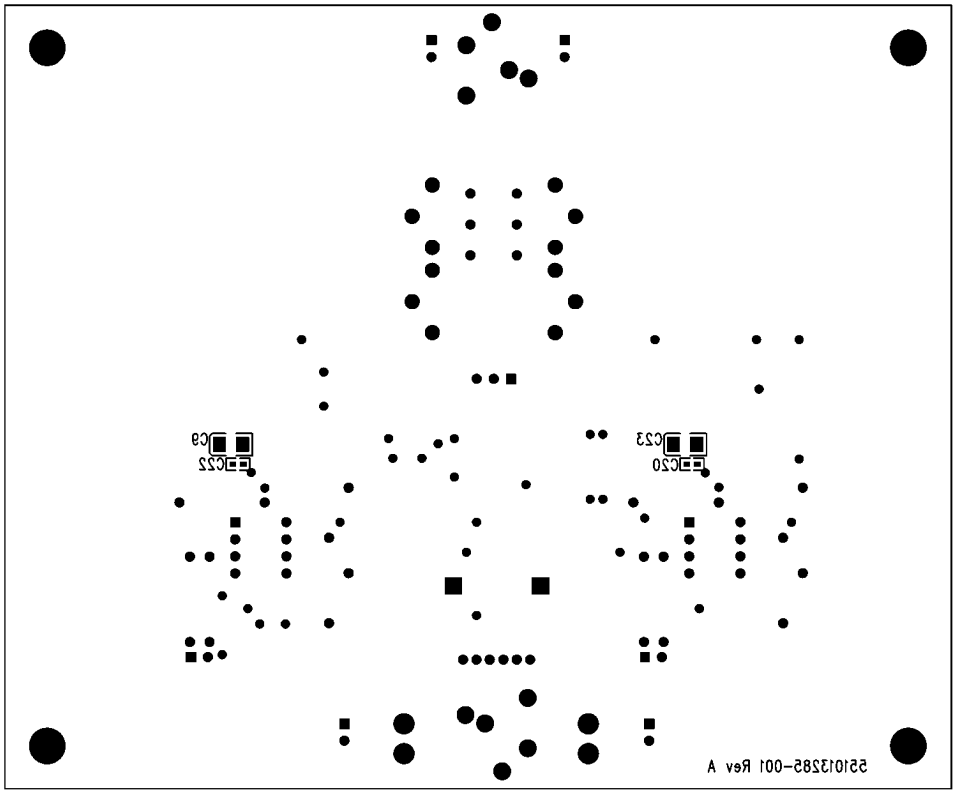

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Figure 6. Bottom Silk Layer

Typical Performance

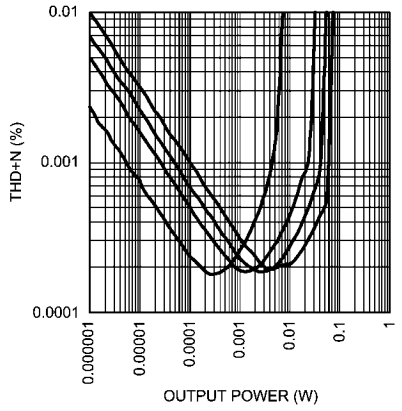

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FIGURE 7: THD+N vs Output Power LME49720/LME49600 headphone amplifier into (from top to bottom at 0.1mW): 16Ω, 32Ω, 64Ω, 300Ω (V_S = ±3V, f = 100Hz, 22Hz ≤ BW ≤ 22kHz)

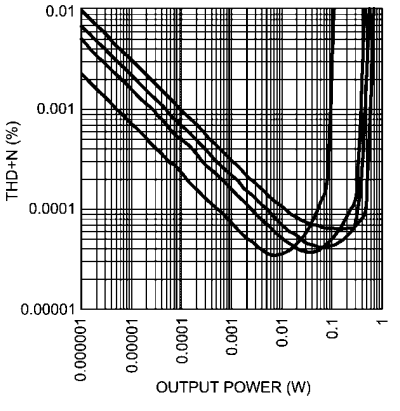

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FIGURE 8: THD+N vs Output Power LME49720/LME49600 headphone amplifier into (from top to bottom at 10mW): 16Ω, 32Ω, 64Ω, 300Ω (V_S = ±9V, f = 100Hz, 22Hz ≤ BW ≤ 22kHz)

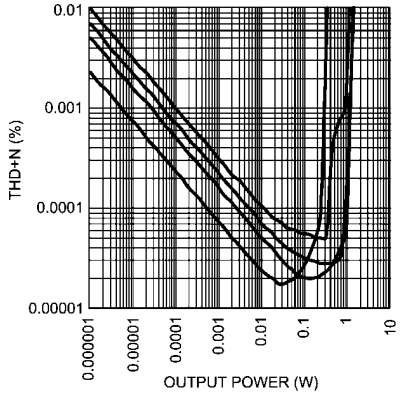

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FIGURE 9: THD+N vs Output Power LME49720/LME49600 headphone amplifier into (from top to bottom at 10mW): 16Ω, 32Ω, 64Ω, 300Ω (V_S = ±15V, f = 100Hz, 22Hz ≤ BW ≤ 22kHz)

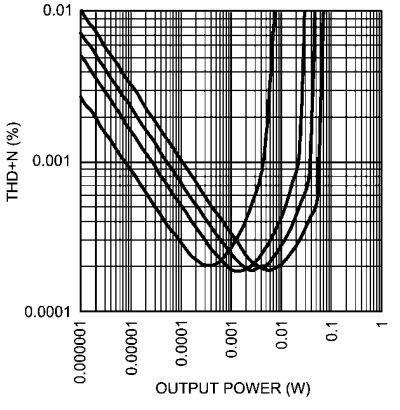

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FIGURE 10: THD+N vs Output Power LME49720/LME49600 headphone amplifier into (from top to bottom at 0.1mW): 16Ω, 32Ω, 64Ω, 300Ω (V_S = ±3V, f = 1kHz, 400Hz ≤ BW ≤ 22kHz)

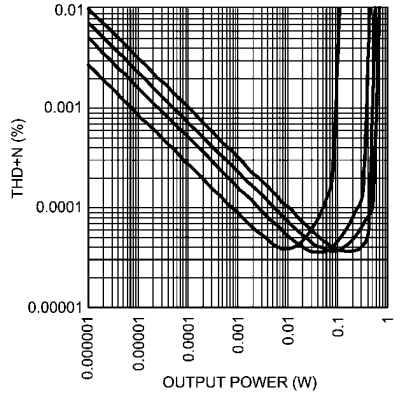

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FIGURE 11: THD+N vs Output Power LME49720/LME49600 headphone amplifier into (from top to bottom at 10mW): 16Ω, 32Ω, 64Ω, 300Ω (V_S = ±9V, f = 1kHz, 400Hz ≤ BW ≤ 22kHz)FIGURE

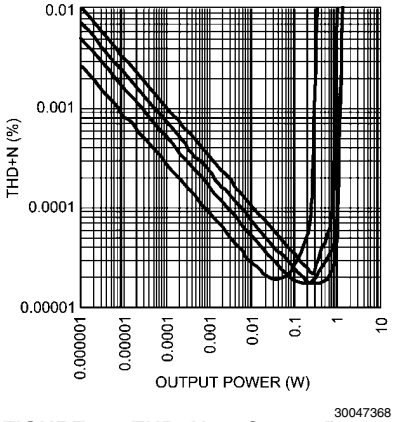

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FIGURE 12: THD+N vs Output Power LME49720/LME49600 headphone amplifier into (from top to bottom at 10mW): 16Ω, 32Ω, 64Ω, 300Ω (V_S = ±15V, f = 1kHz, 400Hz ≤ BW ≤ 22kHz)

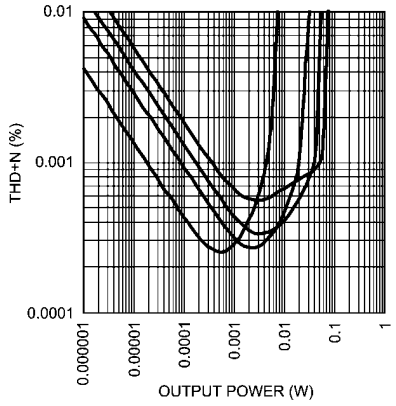

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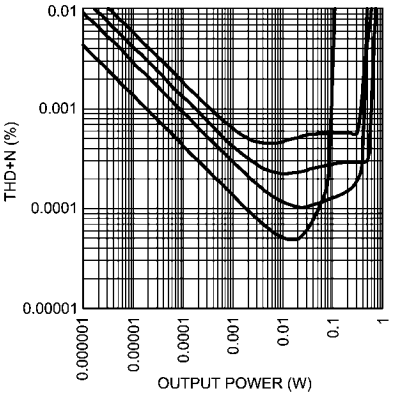
FIGURE 13: THD+N vs Output Power
LME49720/LME49600 headphone amplifier
into (from top to bottom at 0.1mW): 16Ω, 32Ω, 64Ω, 300Ω
(V_S = ±3V, f = 10kHz, 400Hz ≤ BW ≤ 80kHz)



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14: THD+N vs Output Power
LME49720/LME49600 headphone amplifier
into (from top to bottom at 20mW): 16Ω, 32Ω, 64Ω, 300Ω
(V_S = ±9V, f = 10kHz, 400Hz ≤ BW ≤ 80kHz)

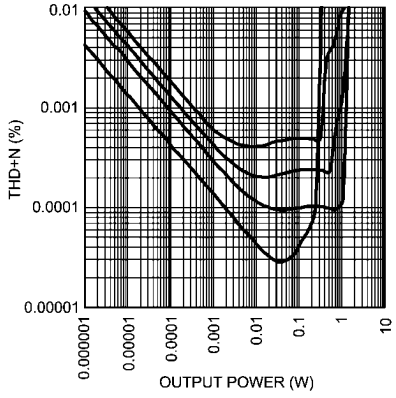

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FIGURE 15: THD+N vs Output Power
LME49720/LME49600 headphone amplifier
into (from top to bottom at 20mW): 16Ω, 32Ω, 64Ω, 300Ω
(V_S = ±15V, f = 10kHz, 400Hz ≤ BW ≤ 80kHz)

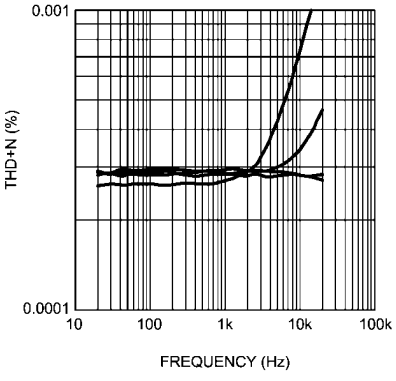

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FIGURE 16: THD+N vs Frequency
LME49720/LME49600 headphone amplifier
into (from top to bottom at 5kHz): 16Ω at 3mW, 32Ω at 3mW
300Ω at 0.3mW, and 64Ω at 1.5mW
(V_S = ±3V, < 10Hz ≤ BW ≤ 80kHz)

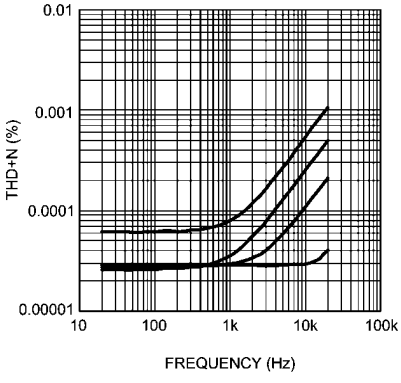

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FIGURE 17: THD+N vs Frequency
LME49720/LME49600 headphone amplifier
into (from top to bottom at 5kHz): 16Ω at 100mW, 32Ω at 100mW
64Ω at 35mW, and 300Ω at 8mW
(V_S = ±9V, < 10Hz ≤ BW ≤ 80kHz)

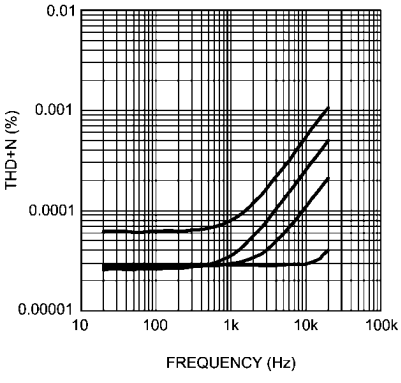

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FIGURE 18: THD+N vs Frequency
LME49720/LME49600 headphone amplifier
into (from top to bottom at 5kHz): 16Ω at 100mW, 32Ω at 100mW
64Ω at 150mW, and 300Ω at 30mW
(V_S = ±15V, < 10Hz ≤ BW ≤ 80kHz)

Revision History

Rev	Date	Description
1.0	02/29/08	Initial release.

Notes

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